

-60V P-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ◇ Surface-mounted package
- ◇ Advanced TRENCH cell design

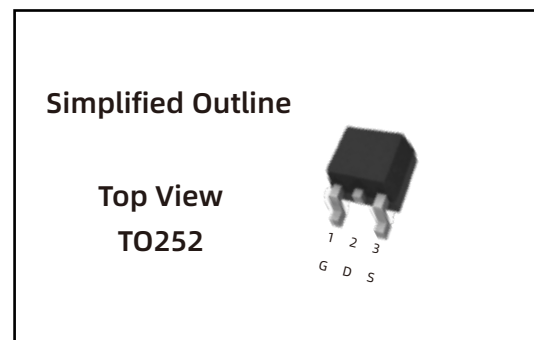
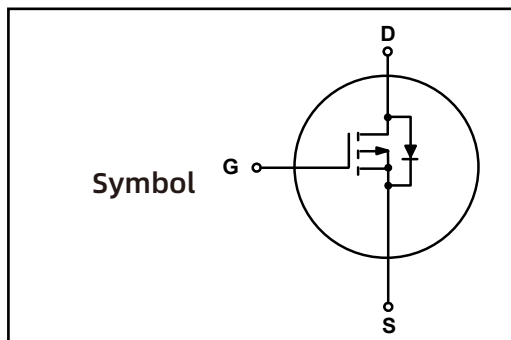
1.2 Applications

- ◇ LCD TV appliances
- ◇ LCDM appliances
- ◇ High power inverter system

1.3 Quick reference

- ◇ $BV \cong -60\text{ V}$
- ◇ $P_{\text{tot}} \cong 62.5\text{ W}$
- ◇ $I_D \cong -18\text{ A}$
- ◇ $R_{\text{DS(ON)}} \cong 88\text{ m}\Omega @ V_{\text{GS}} = -10\text{ V}$
- ◇ $R_{\text{DS(ON)}} \cong 99\text{ m}\Omega @ V_{\text{GS}} = -4.5\text{ V}$

2. Pin Description



3. Marking Information

Product Name	Marking
LN770P060J	LN770P060J CYWWZZ XXXXXX

4.Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	$T_C = 25\text{ }^\circ\text{C}$	-	-60	V
V_{GS}	Gate-Source Voltage	$T_C = 25\text{ }^\circ\text{C}$	-	± 20	V
I_D^*	Drain Current (DC)	$T_C = 25\text{ }^\circ\text{C}, V_{GS} = -10\text{ V}$	-	- 18	A
		$T_C = 100\text{ }^\circ\text{C}, V_{GS} = -10\text{ V}$		- 11.5	A
$I_{DM}^{*,**,***}$	Drain Current (Pulsed)	$T_C = 25\text{ }^\circ\text{C}, V_{GS} = -10\text{ V}$	-	- 48	A
P_{tot}	Drain power dissipation	$T_C = 25\text{ }^\circ\text{C}$	-	62.5	W
T_{stg}	Storage Temperature		-55	150	$^\circ\text{C}$
T_J	Junction Temperature		-	150	$^\circ\text{C}$
I_S	Continuous-Source Current	$T_C = 25\text{ }^\circ\text{C}$	-	- 18	A
E_{AS}^*	Single Pulsed Avalanche Energy	$V_{DD} = -50\text{ V}, L = 1.0\text{ mH}$	-	40.5	mJ
$R_{\theta JA}^*$	Thermal Resistance- Junction to Ambient		-	38.9	$^\circ\text{C}/\text{W}$
$R_{\theta JC}^*$	Thermal Resistance- Junction to Case		-	2	

Notes :

* Surface Mounted on 1 in² pad area, t 10≤ sec

** Pulse width ≤ 300 μs, duty cycle ≤ 2 %

5.Ordering Code

Product Name	Package	Reel Size	Tape width	Quantity	Note
LN055P060J	T0252			2500	

Note: COMTECH defines “ Green ” as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC / JEDEC J-STD-020C)

6. Electrical Characteristics ($T_A=25^\circ$ Unless Otherwise Noted)

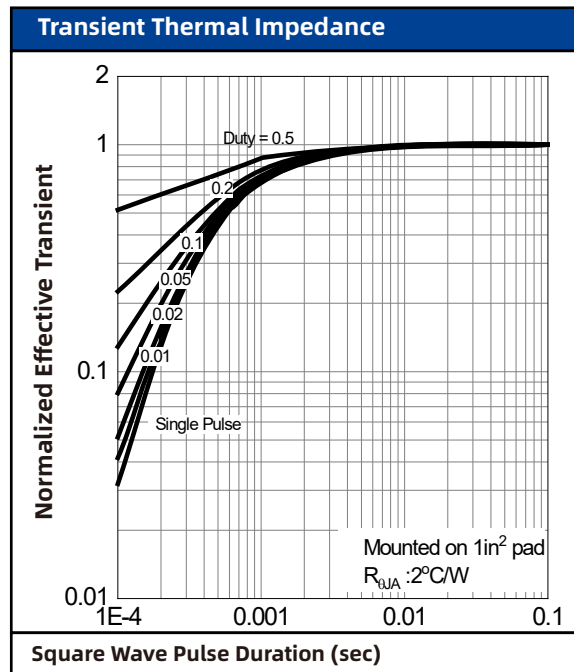
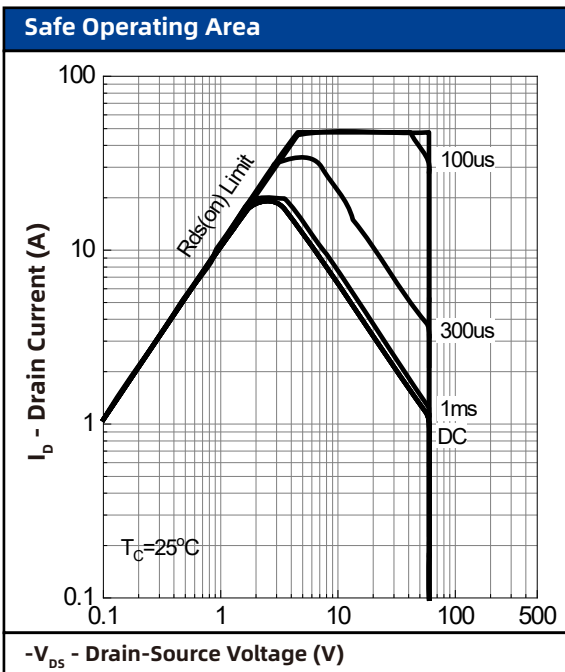
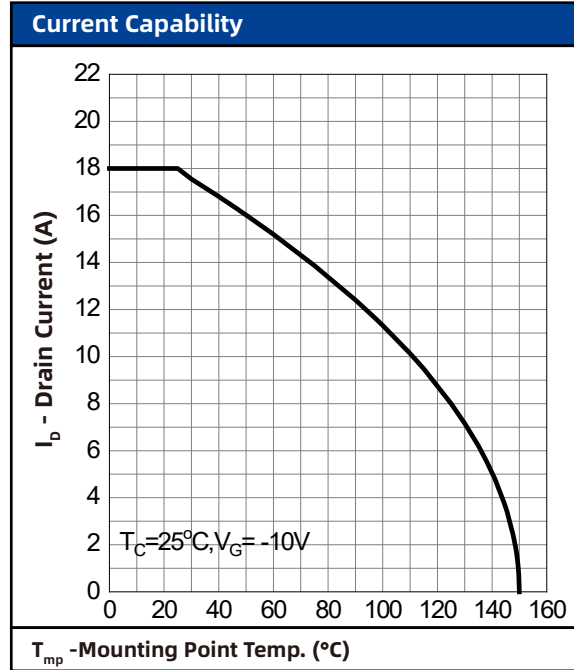
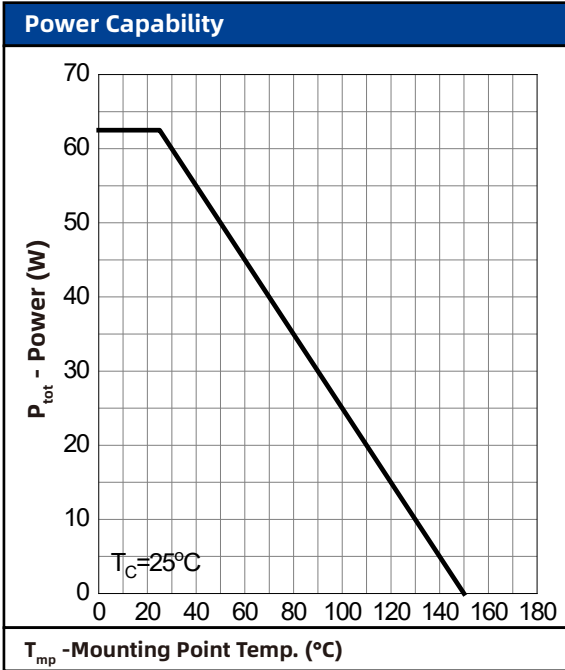
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_{DS} = -250\ \mu\text{A}$	-60	-	-	V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{DS} = -250\ \mu\text{A}$	-1	-	-3	V
I_{DSS}	Drain Leakage Current	$V_{DS} = -48\text{ V}, V_{GS} = 0\text{ V}$	-	-	-1	μA
I_{GSS}	Gate Leakage Current	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$	-	-	± 100	nA
$R_{DS(ON)}^a$	On-State Resistance	$V_{GS} = -10\text{ V}, I_{DS} = -5\text{ A}$	-	78	88	m Ω
		$V_{GS} = -4.5\text{ V}, I_{DS} = -2.5\text{ A}$	-	95	99	
Diode Characteristics						
V_{SD}^a	Diode Forward Voltage	$I_{SD} = -5\text{ A}, V_{GS} = 0\text{ V}$	-	-	-1.2	V
t_{rr}	Reverse Recovery Time	$I_{DS} = -5\text{ A}$	-	15	-	nS
Q_{rr}	Reverse Recovery Charge	$dI_{SD}/dt = 100\text{ A}/\mu\text{s}$	-	14	-	nC
Dynamic Characteristics^b						
C_{ISS}	Input Capacitance	$V_{GS} = 0\text{ V}, V_{DS} = -30\text{ V}$ Frequency = 1 MHz	-	929	-	pF
C_{OSS}	Output Capacitance		-	44	-	
C_{rSS}	Reverse Transfer Capacitance		-	37	-	
$t_d(on)$	Turn-on Delay Time	$V_{DS} = -30\text{ V}, V_{GEN} = -10\text{ V},$ $R_G = 3.9\ \Omega, R_L = 6\ \Omega,$ $I_{DS} = -5\text{ A}$	-	6.4	-	nS
t_r	Turn-on Rise Time		-	11	-	
$t_d(off)$	Turn-off Delay Time		-	22	-	
t_f	Turn-off Fall Time		-	18	-	
Gate Charge Characteristics^b						
Q_g	Total Gate Charge	$V_{DS} = -30\text{ V}, V_{GS} = -10\text{ V},$ $I_{DS} = -5\text{ A}$	-	16	-	nC
Q_{gs}	Gate-Source Charge		-	4.4	-	
Q_{gd}	Gate-Drain Charge		-	2	-	

Notes :

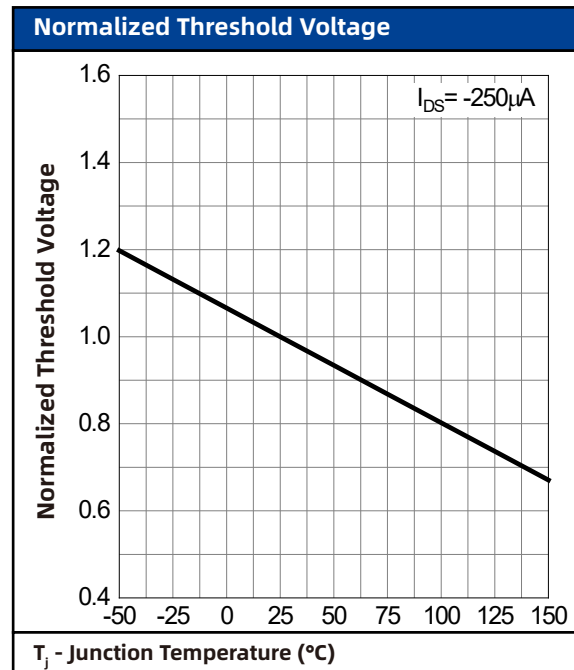
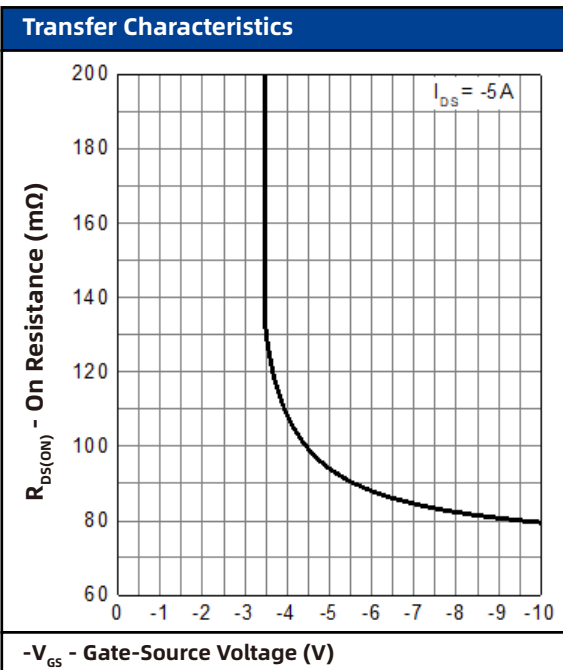
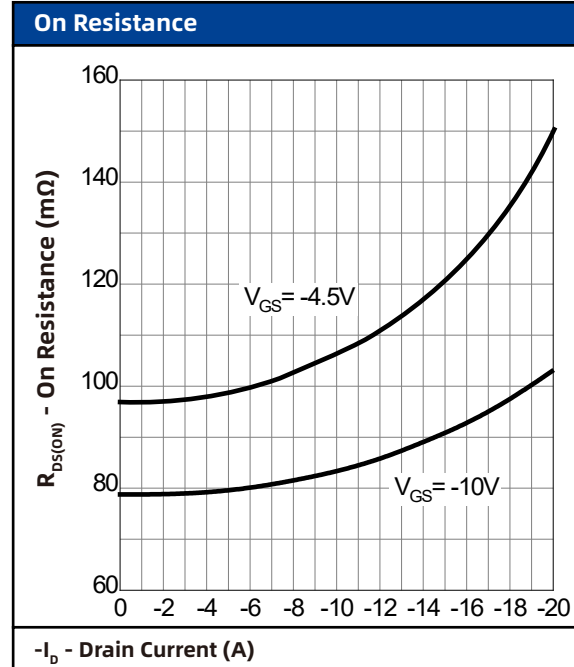
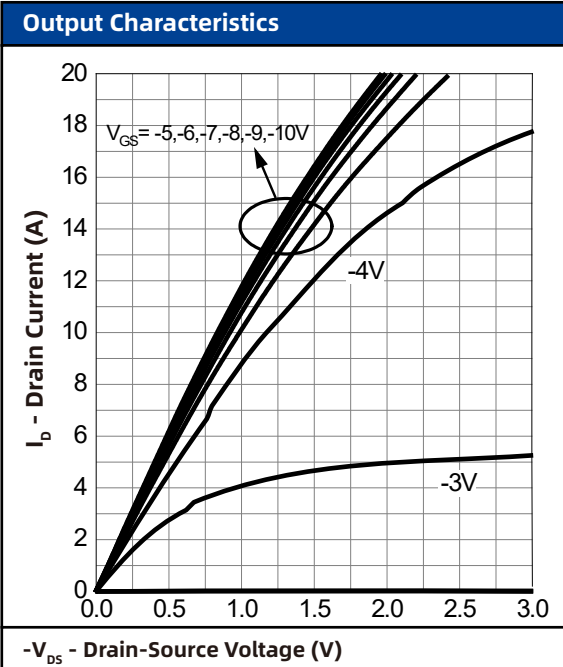
a : Pulse test ; pulse width $\leq 300\ \mu\text{s}$, duty cycle $\leq 2\%$

b : Guaranteed by design, not subject to production testing

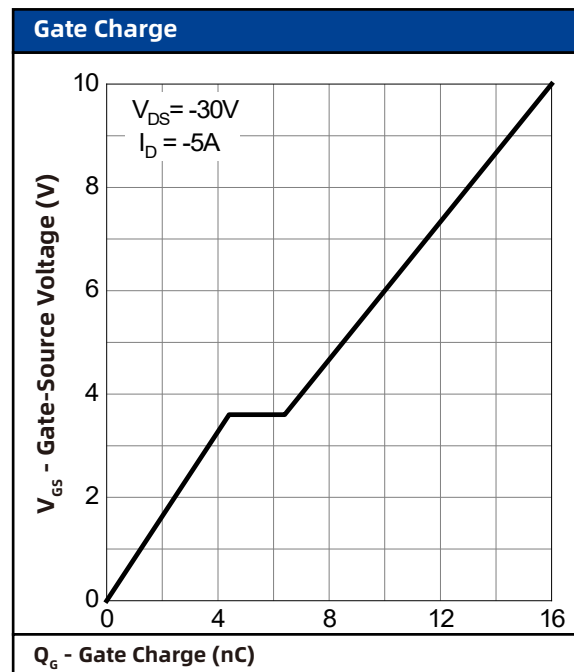
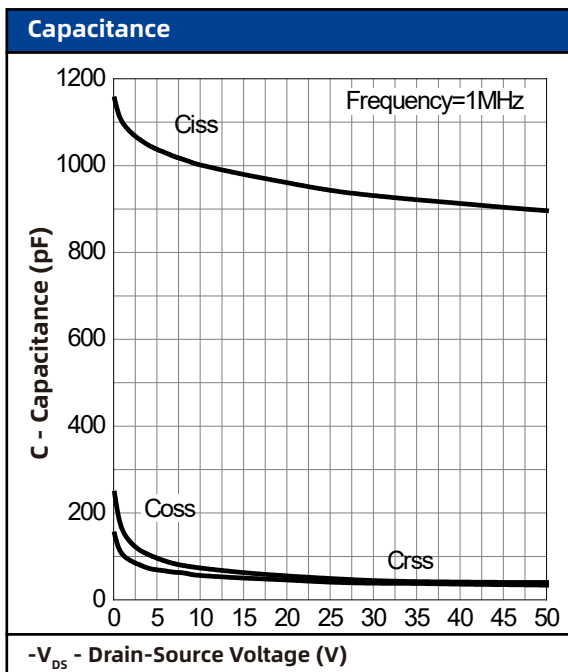
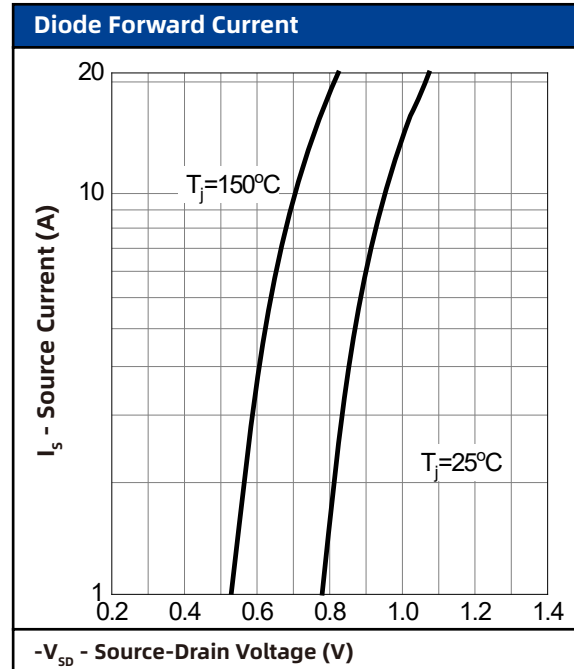
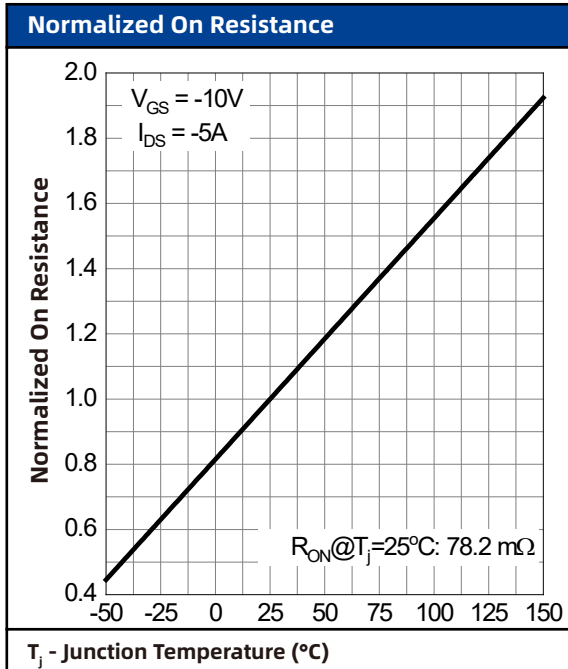
7. Typical Characteristics



7. Typical Characteristics (cont.)

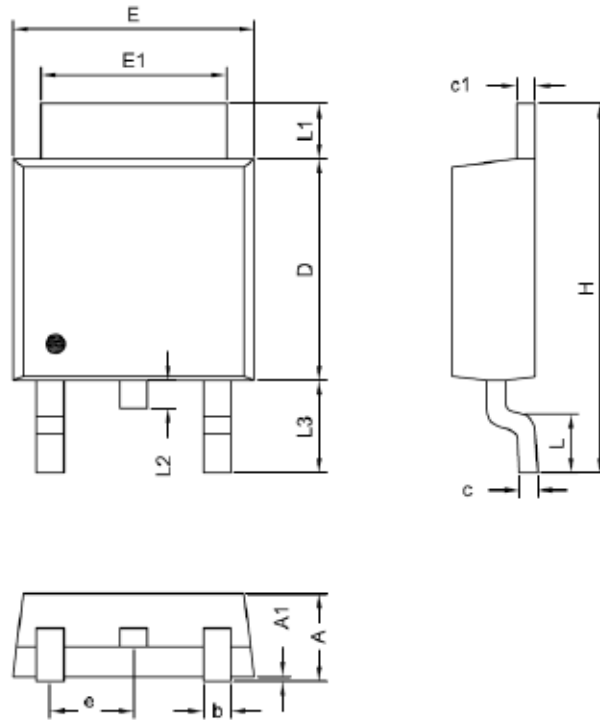


7. Typical Characteristics (cont.)



8. Package Dimensions

T0252-3L



Symbol	Dimensions In Millimeters	
	MIN.	MAX.
A	2.19	2.38
A1	0.02	0.13
D	5.30	6.40
E	6.35	6.80
E1	5.20	5.50
c	0.40	0.60
c1	0.40	0.60
b	0.55	0.85
e	2.30BCS	
L	1.00	1.80
L1	0.70	1.80
L2	0.70BCS	
L3	2.40	2.80
H	9.20	10.40